

Standard Recovery Diodes, Generation 2 DO-5 (DO-203AB) (Stud Version), 80 A



FEATURES
• High surge of
• Designed for
• Stud cathod



- surge current capability
- gned for a wide range of applications
- cathode and stud anode version
- Wire version available
- Low thermal resistance
- · Designed and qualified for multiple level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

- Battery charges
- Converters
- Power supplies
- · Machine tool controls
- Welding

PRIMARY CHARACTERISTICS			
I _{F(AV)}	80 A		
Package	DO-5 (DO-203AB)		
Circuit configuration	Single		

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
1		80	A	
I _{F(AV)}	T _C	140	°C	
I _{F(RMS)}		126	Α	
I _{FSM}	50 Hz	1500	Δ.	
	60 Hz	1570	— A	
l²t	50 Hz	11 250	A2-	
	60 Hz	10 230	— A ² s	
V _{RRM}	Range	400 to 1200	V	
TJ		-55 to +180	°C	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 150 °C mA	
	40	400	500		
VS-80PF(R)(W)	80	800	960	9	
	120	1200	1440		



FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current	1	190° condu	ction, half sine w	21/0	80	А
at case temperature	I _{F(AV)}	160 Conduc	Clion, nan sine w	ave	140	°C
Maximum RMS forward current	I _{F(RMS)}				126	Α
		t = 10 ms	No voltage		1500	A
Maximum peak, one-cycle forward,	l=	t = 8.3 ms	reapplied	Sinusoidal half wave, initial T _J = 150 °C	1570	
non-repetitive surge current	IFSM	t = 10 ms	100 % V _{RRM} reapplied		1260	
		t = 8.3 ms			1320	
	l ² t	t = 10 ms	No voltage		11 250	A ² s
Maximum I ² t for fusing		t = 8.3 ms	reapplied		10 230	
Waximum I-t for fusing		t = 10 ms	100 % V _{RRM}		7950	
		t = 8.3 ms	reapplied		7200	
Maximum I ² √t for fusing	I²√t	t = 0.1 ms to 10 ms, no voltage reapplied		112 500	A²√s	
Low level value of threshold voltage	V _{F(TO)}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum		0.73	V	
Low level value of forward slope resistance	r _f	(16.7 % x π x $I_{F(AV)} < I < \pi$ x $I_{F(AV)}$), $T_J = T_J$ maximum 3.0 m Ω		mΩ		
Maximum forward voltage drop	V_{FM}	I_{pk} = 220 A, T_J = 25 °C, t_p = 400 μ s rectangular wave 1.40 V		V		

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction operating and storage temperature range	T _J , T _{Stg}		-55 to +180	°C	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.30	K // //	
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25	K/W	
		Not lubricated threads, tighting on nut (1)	3.4 (30)		
Allowable mounting torque		Lubricated threads, tighting on nut (1)	2.3 (20)	N⋅m	
		Not lubricated threads, tighting on Hexagon (2)	4.2 (37)	(lbf · in)	
		Lubricated threads, tighting on Hexagon (2)	3.2 (28)		
Approximate weight			15.8	g	
Approximate weight			0.56	OZ.	
Case style		See dimensions - link at the end of datasheet	DO-5 (D0	D-203AB)	

Notes

⁽²⁾ Torque must be applicable only to Hexagon and not to plastic structure, recommended for holed heatsink

△R _{thJC} CONDUCTION					
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.14	0.10			
120°	0.16	0.17			
90°	0.21	0.22	$T_J = T_J$ maximum	K/W	
60°	0.30	0.31			
30°	0.50	0.50			

Note

⁽¹⁾ Recommended for pass-through holes

[•] The table above shows the increment of thermal resistance RthJC when devices operate at different conduction angles than DC

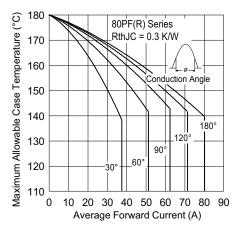


Fig. 1 - Current Ratings Characteristics

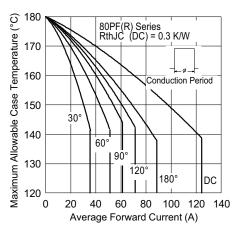


Fig. 2 - Current Ratings Characteristics

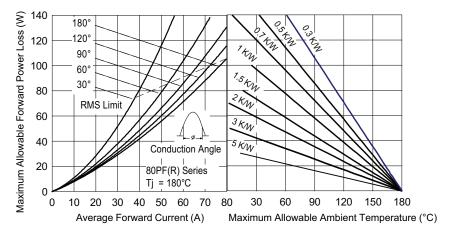


Fig. 3 - Forward Power Loss Characteristics

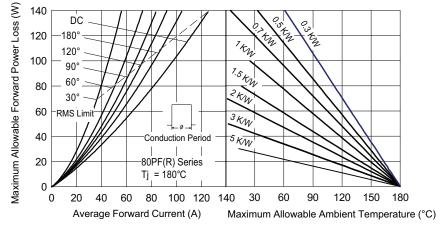
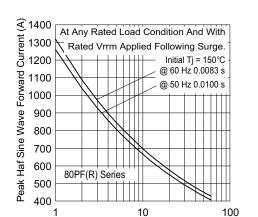


Fig. 4 - Forward Power Loss Characteristics



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Number Of Equal Amplitude Half Cycle Current Pulses (N)

Fig. 5 - Maximum Non-Repetitive Surge Current

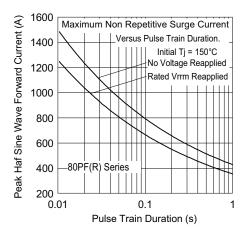


Fig. 6 - Maximum Non-Repetitive Surge Current

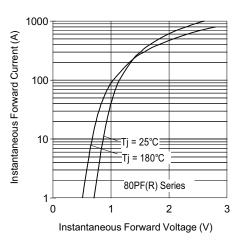


Fig. 7 - Forward Voltage Drop Characteristics

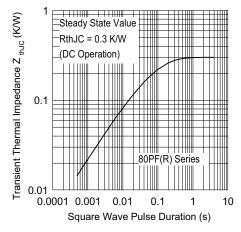
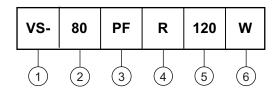


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - • 80 = standard device

 82 = isolated lead on standard terminal with silicone sleeve available for 1200 V only (red = reverse polarity)
(blue = normal polarity)

3 - PF = plastic package

None = stud normal polarity (cathode to stud)

• R = stud reverse polarity (anode to stud)

5 - Voltage code x 10 = V_{RRM} (see Voltage Ratings table)

 None = standard terminal (see dimensions for 80PF(R)... - link at the end of datasheet)

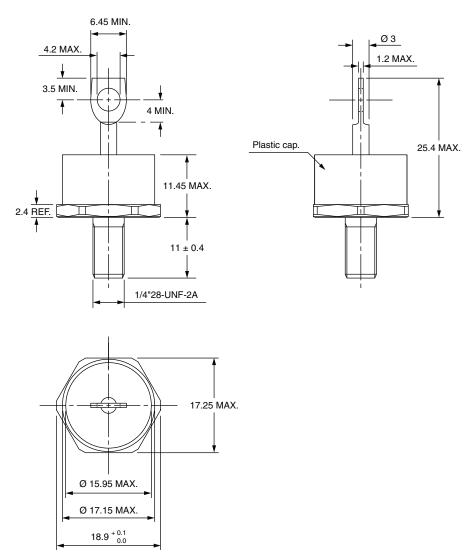
> W = wire terminal (see dimensions for 80PF(R)...W - link at the end of datasheet)

LINKS TO RELATED DOCUMENTS		
Dimensions	www.vishay.com/doc?95345	



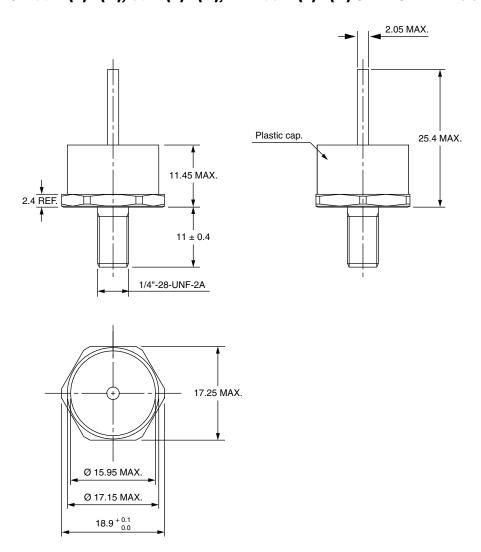
DO-203AB (DO-5) for 50PF(R)...(W), 80PF(R)...(W), and 95PF(R)...(W) Series

DIMENSIONS FOR 80PF(R), 50PF(R), AND 95PF(R) SERIES in millimeters



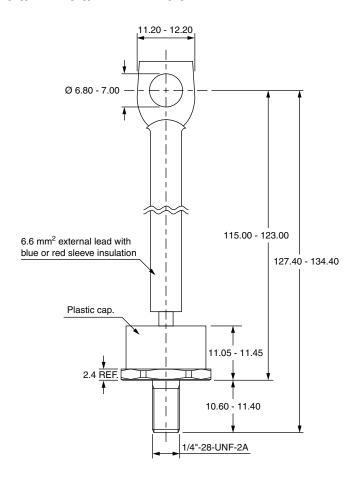


DIMENSIONS FOR 80PF(R)...(W), 50PF(R)...(W), AND 95PF(R)...(W) SERIES in millimeters





DIMENSIONS FOR 52PF(R), 82PF(R), AND 97PF(R) SERIES in millimeters





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